

#### **Features**

- · Trench Power LV MOSFET Technology
- High Density Cell Design for Low R<sub>DS(ON)</sub>
- · High Speed Switching
- · Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

### **Maximum Ratings**

Operating Junction Temperature Range: -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

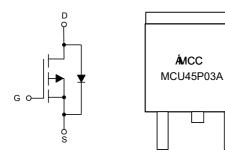
Thermal Resistance: 2°C/W Junction to Case

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Volltage		V <sub>GS</sub>	±25	V	
Continuous Drain Current	T <sub>C</sub> =25°C	1	-45	Α	
	T <sub>C</sub> =85°C	⊢ I <sub>D</sub>	-32		
Pulsed Drain Current <sup>(1)</sup>	I <sub>DM</sub>	-175	Α		
Total Power Dissipation	P <sub>D</sub>	62.5	W		
Single Pulsed Avalanche Energy		E <sub>AS</sub>	145	mJ	

#### Note:

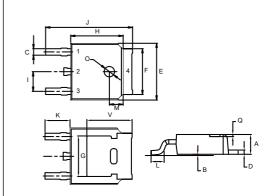
1. Pulse Test: Pulse Width≤300µs,Duty Cycle ≤2%.

## **Internal Structure and Marking Code**



# P-CHANNEL MOSFET

# **DPAK(TO-252)**



- 1. Gate
- 2,4. Drain
- 3. Source

DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.087	0.094	2.20	2.40		
В	0.000	0.005	0.00	0.13		
С	0.026	0.034	0.66	0.86		
D	0.018	0.023	0.46	0.58		
E	0.256	0.264	6.50	6.70		
F	0.201	0.215	5.10	5.46		
G	0.190		4.83		TYP.	
Н	0.236	0.244	6.00	6.20		
ı	0.086	0.094	2.18	2.39		
J	0.386	0.409	9.80	10.40		
K	0.114		2.90		TYP.	
L	0.055	0.067	1.40	1.70		
M	0.063		1.60		TYP.	
0	0.043	0.051	1.10	1.30		
Q	0.000	0.012	0.00	0.30		
V	0.211		5.35		TYP.	

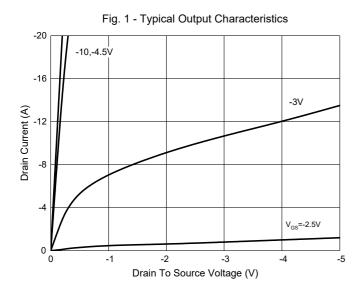


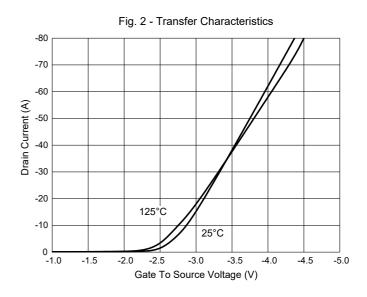
# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

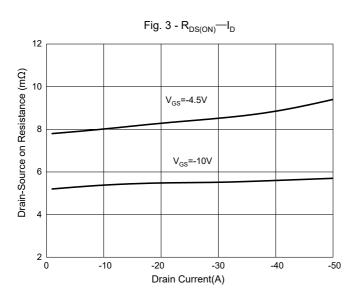
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			•				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-30			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±25V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			-1	μA	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.2	-1.8	-2.8	V	
Drain-Source On-Resistance		V <sub>GS</sub> =-20V, I <sub>D</sub> =-20A		4.8	7	mΩ	
		V <sub>GS</sub> =-10V, I <sub>D</sub> =-15A		5.5	8		
	R <sub>DS(on)</sub>	V <sub>GS</sub> =-6V, I <sub>D</sub> =-12A		6.5	12		
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-12A		8	13	1	
Diode Characteristics			•				
Continuous Body Diode Current	Is				-45	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-20A			-1.2	V	
Reverse Recovery Time	t <sub>rr</sub>	- I <sub>S</sub> =-20A, dI <sub>F</sub> /dt=100A/μs		18		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	1 <sub>S</sub> 20Α, αι <sub>F</sub> /αι-100Α/μS		7.8		nC	
Dynamic Characteristics	•						
Input Capacitance	C <sub>iss</sub>			2152			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V,f=1MHz		308		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			242			
Total Gate Charge	$Q_g$			40			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-15V,V <sub>GS</sub> =10V,I <sub>D</sub> =-12A		8.4		nC	
Gate-Drain Charge	$Q_{gd}$			8.6			
Turn-On Delay Time	t <sub>d(on)</sub>			8			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =-15V, V <sub>GS</sub> =-10V,		19		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =2.5 $\Omega$ , $I_D$ =-1A		75			
Turn-Off Fall Time	t <sub>f</sub>			46			

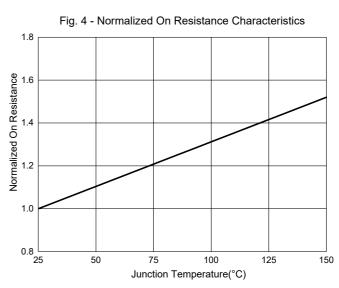


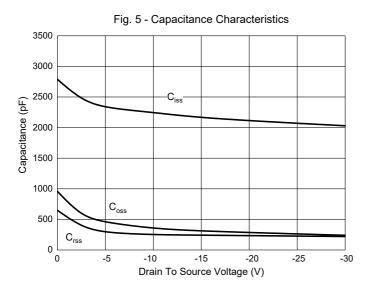
#### **Curve Characteristics**

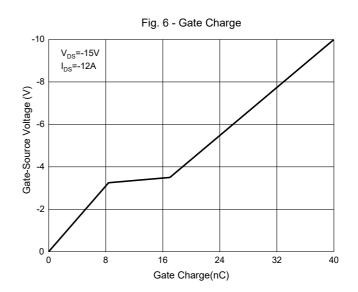






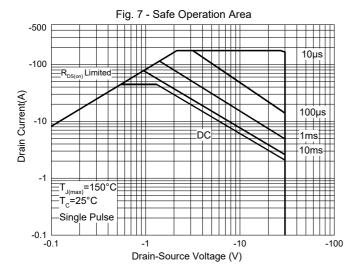








#### **Curve Characteristics**





#### **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel	

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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